

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	2	"20020028314"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 20:18
S2	9	"6447604"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/16 08:46
S3	27	"5771110"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/16 08:47
S4	11	"1143047"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/16 08:48
S5	19	"447047"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/16 08:47
S6	12	"1143047"	US-PGPUB; USPAT; USOCR; EPO; DERWENT	OR	OFF	2006/03/16 08:48
S7	94588	"silicon carbide"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2006/03/16 08:55
S8	2	"thermal radiation absorption layer"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2006/03/16 08:55
S9	1	S7 and S8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2006/03/16 08:56
S10	96	"radiation absorption layer"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2006/03/16 08:56

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S11	3	S7 and S10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2006/03/16 10:08
S12	1	"1184897"	EPO	OR	OFF	2006/03/16 10:09
S13	1	"1280190"	EPO	OR	OFF	2006/03/16 10:08
S14	7	"6214108"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 12:43
S15	2	"6824610"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 12:43
S16	226	117/94.ccls.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 20:19
S17	233	117/90.ccls.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 20:19
S18	16	"thermal absorption layer"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 20:19
S19	0	S16 and S18	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 20:19
S20	0	S17 and S18	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 20:28
S21	2842	"MOVPE"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 20:28
S22	0	S18 and S21	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:13
S23	372	117/104.ccls.	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:13

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S24	0	S18 and S23	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:13
S25	8509	"absorption layer"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:13
S26	0	S23 and S25	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:14
S27	1627	"radiation layer"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:14
S28	0	S23 and S27	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:14
S29	25093	"TEOS"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:14
S30	663	"TEOS oxide layer"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:15
S31	0	S23 and S30	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:15
S32	0	S21 and S30	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:15
S33	84932	"siC"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:48
S34	84932	"SiC"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:48
S35	2842	"movpe"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:48

## EAST Search History

S36	741	S34 and S35	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:48
S37	67689	"backside"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:48
S38	39	S36 and S37	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:49
S39	105914	"polysilicon"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:49
S40	0	S38 and S39	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:49
S41	878176	"silicon"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:49
S42	21590	"doped silicon"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:49
S43	2	S38 and S42	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:58
S44	832	"AlGaInN"	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:58
S45	4	S34 near S44	US-PGPUB; USPAT; USOCR; DERWENT	OR	OFF	2006/03/17 21:58
S46	8788391	TW "447047" A	EPO; JPO	OR	OFF	2006/03/18 14:29
S47	1	"447047"	EPO; JPO	OR	OFF	2006/03/18 14:29
S48	5	"447047"	DERWENT	OR	OFF	2006/03/18 14:29